

Hi-Reliability Optically Coupled Isolator



4N22, 4N23, 4N24 [A] (TX, TXV)

4N47, 4N48, 4N49 [A] (TX, TXV)

Features:

- TO-78 hermetically sealed package
- High current transfer ratio
- 1 kV electrical isolation
- Base contact provided for conventional transistor biasing
- TX and TXV devices processed to MIL-PRF-19500



Description:

Each isolator in this series consists of an infrared emitting diode and a NPN silicon phototransistor, which are mounted in a hermetically sealed TO-78 package. Devices are designed for military and/or harsh environments. The suffix letter "A" denotes the collector is electrically isolated from the case.

The 4N22, 4N22A, 4N23, 4N23A, 4N24, and 4N24A (TX, TXV) devices are processed to MIL-PRF-19500/486.

The 4N47, 4N47A, 4N48, 4N48A, 4N49, and 4N49A (TX, TXV) devices are processed to MIL-PRF-19500/548.

Please contact your local representative or OPTEK for more information.

Applications:

- High-voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment

ORDERING INFORMATION					
Part Number	Isolation Voltage (kV)	CTR % Min / Max	I _F (mA) Typ / Max	V _{CE} (Volts) Max	Processing MIL-PRF-195000
4N22 or 4N22A	1	25 / NA	10 / 40	35	486
4N22TX or 4N22ATX					
4N22TXV or 4N22ATXV					
4N23 or 4N23A		20 / NA			
4N23TX or 4N23ATX					
4N23TXV or 4N23ATXV					
4N24 or 4N24A		40 / NA			
4N24TX or 4N24ATX					
4N24TXV or 4N24ATXV					
4N47 or 4N47A		50 / NA	1 / 40	40	548 548
4N47TX or 4N47ATX					
4N47TXV or 4N47ATXV					
4N48 or 4N48A		100 / 500			
4N48TX or 4N48ATX					
4N48TXV or 4N48ATXV					
4N49 or 4N49A		200 / 1,000			
4N49TX or 4N49ATX					
4N49TXV or 4N49ATXV					

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OPTEK Technology, Inc.
1645 Wallace Drive, Carrollton, TX 75006
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4N47, 4N48, 4N49 [A] (TX, TXV)

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)	
Storage Temperature Range 4N22, 4N22A, 4N23, 4N23A, 4N24, 4N24A (TX, TXV) 4N47, 4N47A, 4N48, 4N48A, 4N49, 4N49A (TX, TXV)	-65° C to +125° C
Operating Temperature Range 4N22, 4N22A, 4N23, 4N23A, 4N24, 4N24A (TX, TXV) 4N47, 4N47A, 4N48, 4N48A, 4N49, 4N49A (TX, TXV)	-55° C to +125° C
Input-to-Output Isolation Voltage	± 1.00 kVDC ⁽¹⁾
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽²⁾
Input Diode	
Forward DC Current (65° C or below)	40 mA
Reverse Voltage	2 V
Peak Forward Current (1 µs pulse width, 300 pps) 4N22, 4N22A, 4N23, 4N23A, 4N24, 4N24A (TX, TXV)	1 A
Power Dissipation	60 mW ⁽³⁾
Output Phototransistor (4N22, 4N22A, 4N23, 4N23A, 4N24, 4N24A)	
Continuous Collector Current	50 mA
Collector-Emitter Voltage	35 V
Collector-Base Voltage	35 V
Emitter-Base Voltage	4 V
Power Dissipation	300 mW ⁽⁴⁾
Output Phototransistor (4N47, 4N47A, 4N48, 4N48A, 4N49, 4N49A)	
Continuous Collector Current	50 mA
Collector-Emitter Voltage	40 V
Collector-Base Voltage	45 V
Emitter-Base Voltage	7.0 V
Power Dissipation	300 mW ⁽⁴⁾

Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
3. Derate linearly 1.0 mW/° C above 65° C.
4. Derate linearly 3.0 mW/° C above 25° C.

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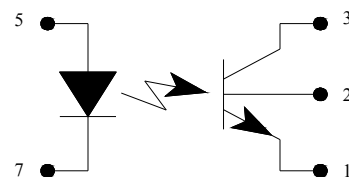
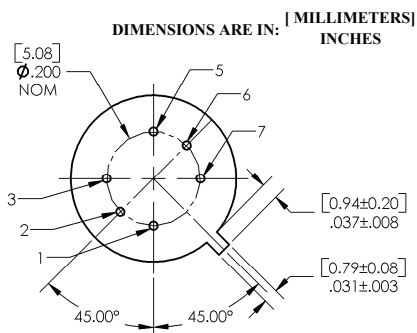
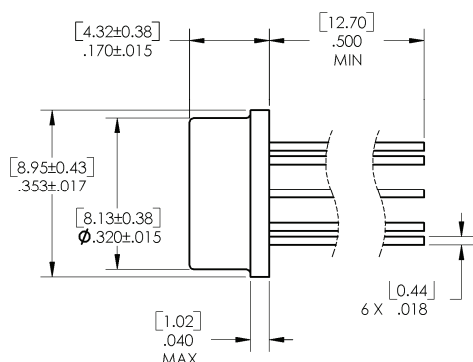
Performance

Electrical Characteristics (T _A = 25°C unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V _F	Forward Voltage					
	4N22, 4N23, 4N24 [A] (TX, TXV)	0.80	-	1.30		I _F = 10.0 mA
	4N22, 4N23, 4N24 [A] (TX, TXV)	1.00	-	1.50		I _F = 10.0 mA, T _A = -55° C ⁽¹⁾
	4N22, 4N23, 4N24 [A] (TX, TXV)	0.70	-	1.20	V	I _F = 10.0 mA, T _A = -100° C ⁽¹⁾
	4N47, 4N48, 4N49 [A] (TX, TXV)	0.80	-	1.50		I _F = 10.0 mA
	4N47, 4N48, 4N49 [A] (TX, TXV)	1.00	-	1.70		I _F = 10.0 mA, T _A = -55° C ⁽¹⁾
	4N47, 4N48, 4N49 [A] (TX, TXV)	0.70	-	1.30		I _F = 10.0 mA, T _A = -100° C ⁽¹⁾
I _R	Reverse Current	-	-	100	μA	V _R = 2.0 V
Output Phototransistor						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	35	-	-	V	I _C = 1.0 mA, I _B = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	40	-	-		I _C = 1.0 mA, I _B = 0, I _F = 0
V _{(BR)CBO}	Collector-Base Breakdown Voltage	35	-	-	V	I _C = 100 μA, I _B = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	45	-	-		I _C = 100 μA, I _B = 0, I _F = 0
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	4	-	-	V	I _E = 100 μA, I _C = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	7	-	-		I _E = 100 μA, I _C = 0, I _F = 0
I _{CEO}	Collector-Emitter Dark Current	-	-	100	nA	V _{CE} = 20 V, I _B = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	-	-	100	μA	V _{CE} = 20 V, I _B = 0, I _F = 0, T _A = 100° C ⁽²⁾
I _{C(OFF)}	Collector-Emitter Dark Current	-	-	100	nA	V _{CE} = 20 V, I _B = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	-	-	100	μA	V _{CE} = 20 V, I _B = 0, I _F = 0, T _A = 100° C ⁽¹⁾
I _{CB(OFF)}	Collector-Base Dark Current	-	-	10	nA	V _{CB} = 20 V, I _E = 0, I _F = 0
	4N22, 4N23, 4N24 [A] (TX, TXV)	-	-	10	nA	V _{CB} = 20 V, I _E = 0, I _F = 0

Notes:

1. Guaranteed but not tested.

2. Sample tested, LTPD = 10.



Pin #	Function	Pin #	Function
1	Emitter	5	Anode
2	Base	6	Open
3	Collector	7	Cathode

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Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Coupled						
$I_{C(ON)}$	On-State Collector Current					
	4N22, 4N22A (TX, TXV)	0.15	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N22, 4N22A (TX, TXV)	2.50	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N22, 4N22A (TX, TXV)	1.00	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N22, 4N22A (TX, TXV)	1.00	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	4N23, 4N23A (TX, TXV)	0.20	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N23, 4N23A (TX, TXV)	6.00	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N23, 4N23A (TX, TXV)	2.50	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N23, 4N23A (TX, TXV)	2.50	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	4N24, 4N24A (TX, TXV)	0.40	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N24, 4N24A (TX, TXV)	10.0	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0$
	4N24, 4N24A (TX, TXV)	4.00	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N24, 4N24A (TX, TXV)	4.00	-	-		$I_F = 10.0\text{ mA}, V_{CE} = 5\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
$I_{CB(ON)}$	4N47, 4N47A (TX, TXV)	0.50	-	-		$I_F = 1.0\text{ Ma}, V_{CE} = 5.0\text{ V}, I_B = 0$
	4N47, 4N47A (TX, TXV)	0.70	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N47, 4N47A (TX, TXV)	0.50	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	4N48, 4N48A (TX, TXV)	1.00	-	5		$I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$
	4N48, 4N48A (TX, TXV)	1.40	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N48, 4N48A (TX, TXV)	1.00	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
$V_{CE(SAT)}$	4N49, 4N49A (TX, TXV)	2.00	-	10		$I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$
	4N49, 4N49A (TX, TXV)	2.80	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$
	4N49, 4N49A (TX, TXV)	2.00	-	-		$I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	4N47, 4N47A (TX, TXV)	-	-	0.30		$I_F = 20\text{ mA}, I_C = 2.5\text{ mA}, I_B = 0$
	4N47, 4N47A (TX, TXV)	-	-	0.30		$I_F = 20\text{ mA}, I_C = 5.0\text{ mA}, I_B = 0$
	4N47, 4N47A (TX, TXV)	-	-	0.30		$I_F = 20\text{ mA}, I_C = 10.0\text{ mA}, I_B = 0$
H_{FE}	4N48, 4N48A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 0.5\text{ mA}, I_B = 0$
	4N48, 4N48A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 1.0\text{ mA}, I_B = 0$
	4N48, 4N48A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 2.0\text{ mA}, I_B = 0$
	4N49, 4N49A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 2.0\text{ mA}, I_B = 0$
	4N49, 4N49A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 2.0\text{ mA}, I_B = 0$
	4N49, 4N49A (TX, TXV)	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 2.0\text{ mA}, I_B = 0$
R_{IO}	DC Current Gain					
	4N22, 4N22A (TX, TXV)	>300	-	-		$V_{CE} = 5.0\text{ V}, I_C = 10.0\text{ mA}, I_F = 0\text{ mA}$
	4N23, 4N23A (TX, TXV)	-	-	-		
	4N24, 4N24A (TX, TXV)	-	-	-		
C_{IO}	Resistance (Input-to-Output)					
	4N22, 4N23, 4N24 [A] (TX, TXV)	10^{11}	-	-	Ω	$V_{I-O} = \pm 1000\text{ VDC}^{(3)}$
C_{IO}	Resistance (Input-to-Output)					
	4N47, 4N48, 4N49 [A] (TX, TXV)	10^{11}	-	-	Ω	$V_{I-O} = \pm 1000\text{ VDC}^{(3)}$
C_{IO}	Capacitance (Input-to-Output)					
	4N47, 4N48, 4N49 [A] (TX, TXV)	-	-	5	pF	$V_{I-O} = 0\text{ V}, f = 1.0\text{ MHz}^{(3)}$

Notes:

1. Guaranteed but not tested.

2. Sample tested, LTPD = 10.

3. Measured with input leads shorted together and output leads shorted together.

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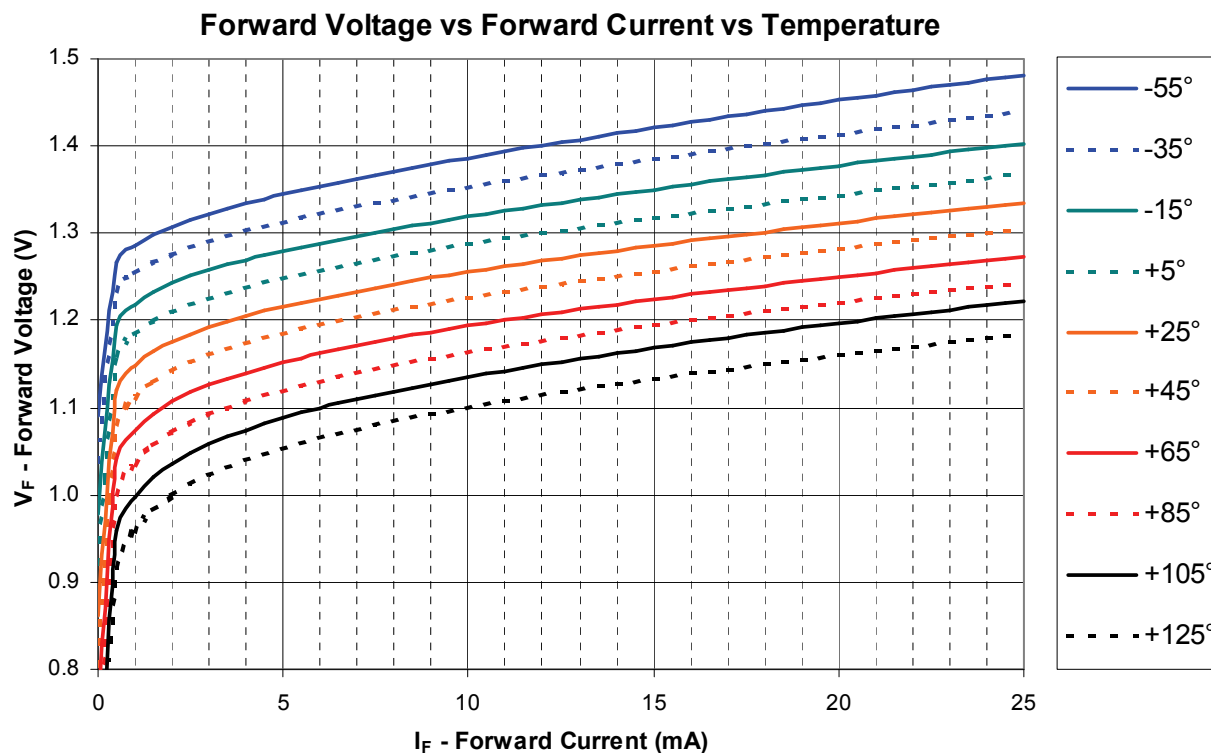
4N22, 4N23, 4N24 [A] (TX, TXV)

4N47, 4N48, 4N49 [A] (TX, TXV)

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Coupled						
T_R	Output Rise Time	-	-	15	μs	$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ mA}$
	4N22A (TX, TXV)	-	-	15		$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ mA}$
	4N23A (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ mA}$
	4N24A (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N47 (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N48 (TX, TXV)	-	-	25		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$
T_F	Output Fall Time	-	-	15	μs	$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N22A (TX, TXV)	-	-	15		$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N23A (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 10.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N24A (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N47 (TX, TXV)	-	-	20		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$
	4N48 (TX, TXV)	-	-	25		$V_{CC} = 10.0\text{ V}$, $I_F = 5.0\text{ mA}$, $R_L = 100\text{ }\Omega$

Typical Performance Curves



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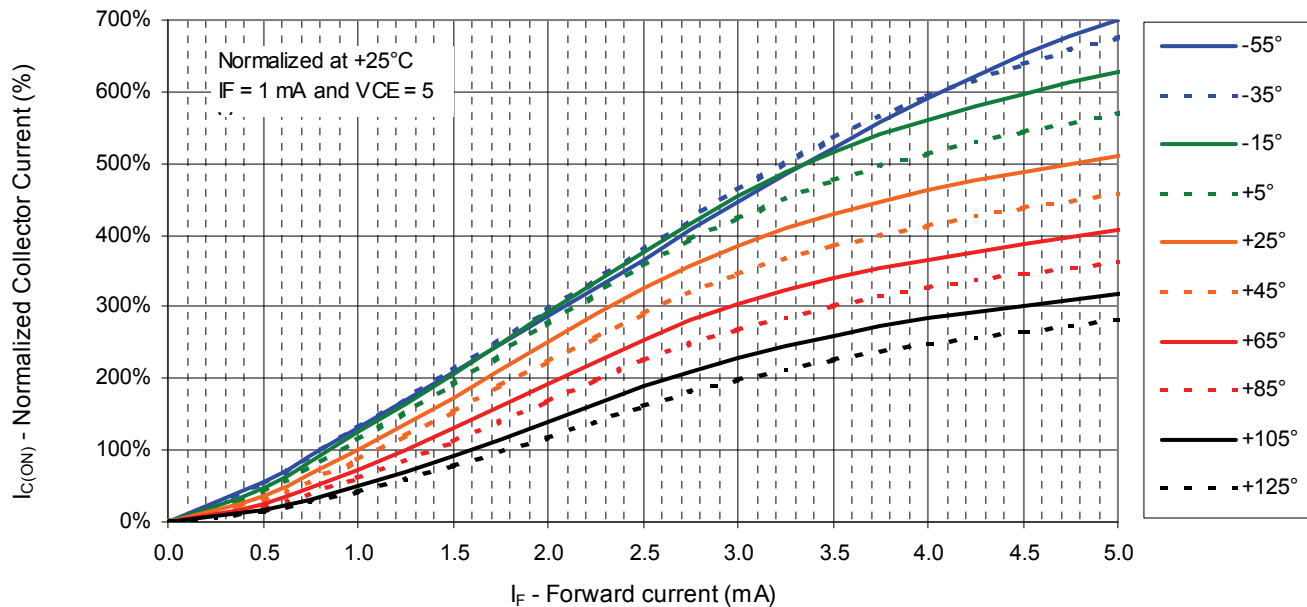


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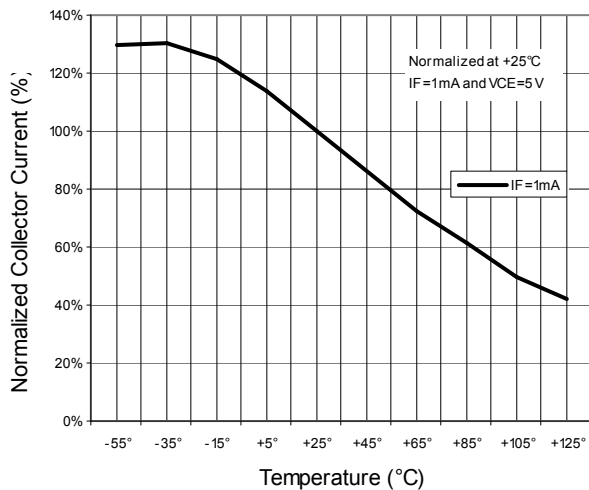
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Typical Performance Curves

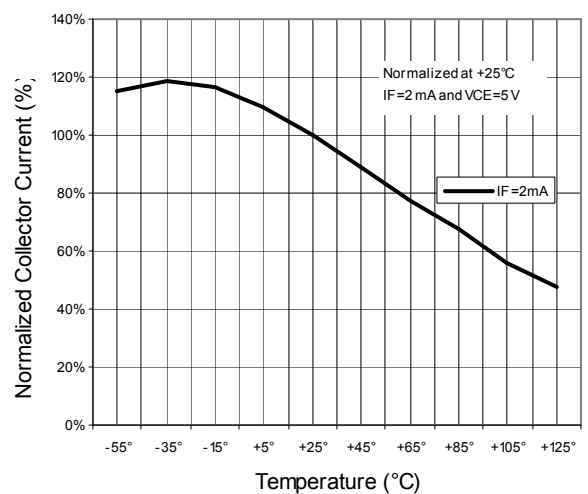
Collector Current vs Forward Current vs Temperature



Normalized Collector Current Vs Temperature



Normalized Collector Current Vs Temperature



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